

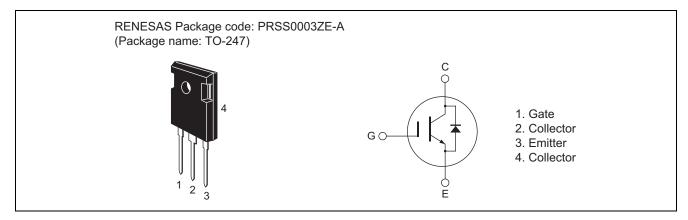
RJH60M6DPQ-E0

600V - 40A - IGBT Application: Inverter R07DS1088EJ0100 Rev.1.00 Jun 27, 2013

Features

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)}=1.8~V$ typ. (at $I_C=40~A,~V_{GE}=15~V,~Ta=25^{\circ}C$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 50 ns typ. (at V_{CC} = 300 V, V_{GE} = 15 V, I_C = 40 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

	Item	Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	I _C	80	A
	Tc = 100°C	I _C	40	A
Collector peak current		I _C (peak) Note1	120	A
Collector to emitter diode forward current		I _{DF}	50	A
Collector to emitter diode forward peak current		I _{DF} (peak) Note1	200	A
Collector dissipation		P _C Note2	298	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	0.42	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	1.07	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current	I _{CES} / I _R			5	μA	$V_{CE} = 600 \text{ V}, V_{GE} = 0$	
/ Diode reverse current	OLO! IX					GE 111 , GE 1	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	5	_	7	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.8	2.3	V	$I_C = 40 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}		2.2	_	V	$I_C = 80 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies		2500	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	175	_	pF	$V_{GE} = 0$	
Reverse transfer capacitance	Cres	_	100	_	pF	f = 1 MHz	
Total gate charge	Qg	_	170	_	nC	V _{GE} = 15 V	
Gate to emitter charge	Qge	_	20	_	nC	V _{CE} = 300 V	
Gate to collector charge	Qgc	_	90	_	nC	$I_{C} = 40 \text{ A}$	
Turn-on delay time	t _{d(on)}	_	55	_	ns	V _{CC} = 300 V	
Rise time	t _r	_	50	_	ns	V _{GE} = 15 V	
Turn-off delay time	t _{d(off)}	_	215	_	ns	$I_{C} = 40 \text{ A}$	
Fall time	t _f	_	50	_	ns	$Rg = 5 \Omega$	
Turn-on energy	E _{on}	_	1.11	_	mJ	Inductive load	
Turn-off energy	E _{off}	_	0.99	_	mJ	-	
Total switching energy	E _{total}	_	2.10	_	mJ	-	
Short circuit withstand time	t _{sc}	6	8	_	μs	Tc = 100 °C	
						$V_{CC} \le 360 \text{ V}, V_{GE} = 15 \text{ V}$	
FRD Forward voltage	V_{F}	_	1.3	1.8	V	$I_F = 40 \text{ A}^{\text{Note3}}$	
FRD reverse recovery time	t _{rr}	_	100	—	ns	$I_F = 40 \text{ A}$	

FRD reverse recovery charge Q_{rr} — 0.22 — FRD peak reverse recovery current I_{rr} — 5.0 —

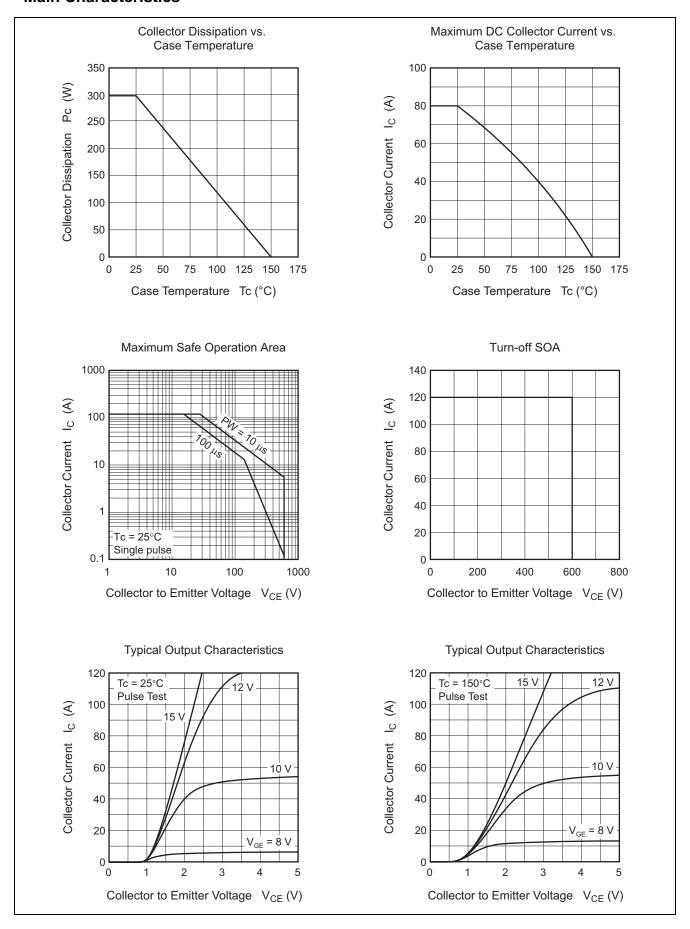
 $I_F = 40 \text{ A}$ $I_F = 40 \text{ A}$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

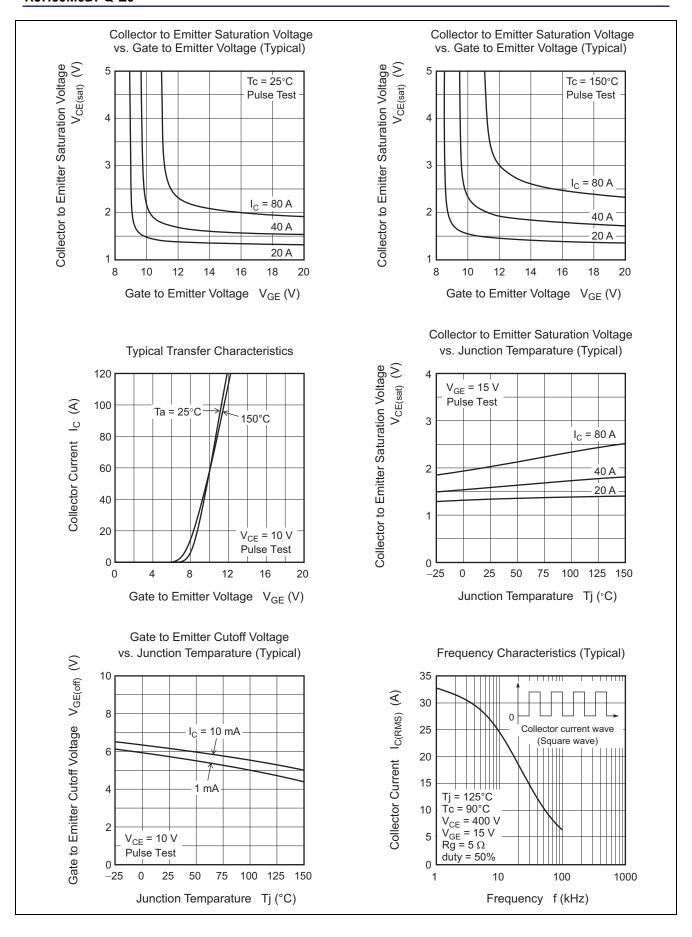
μС

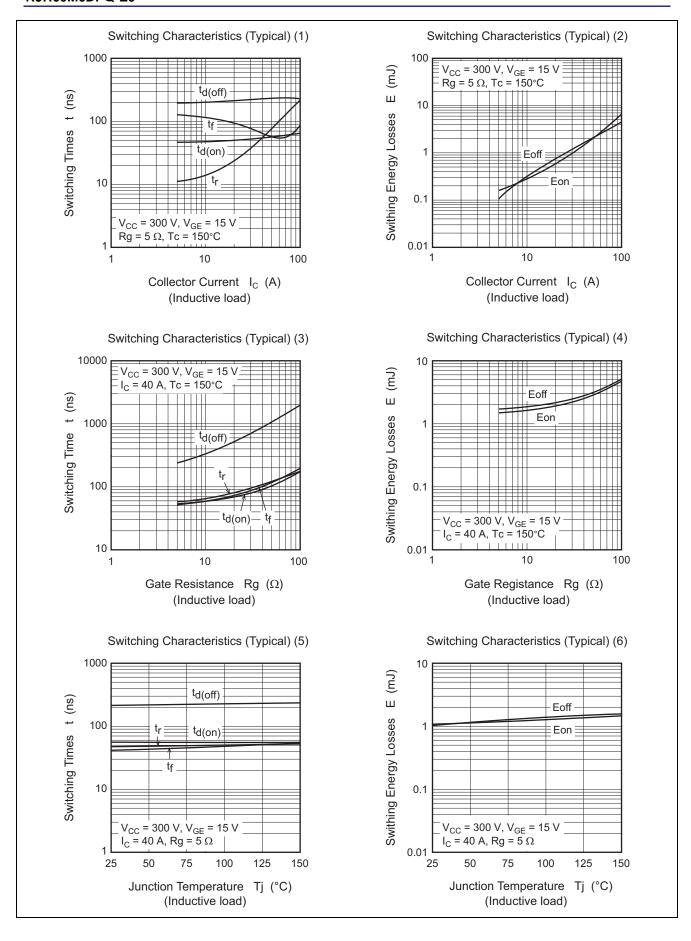
Α

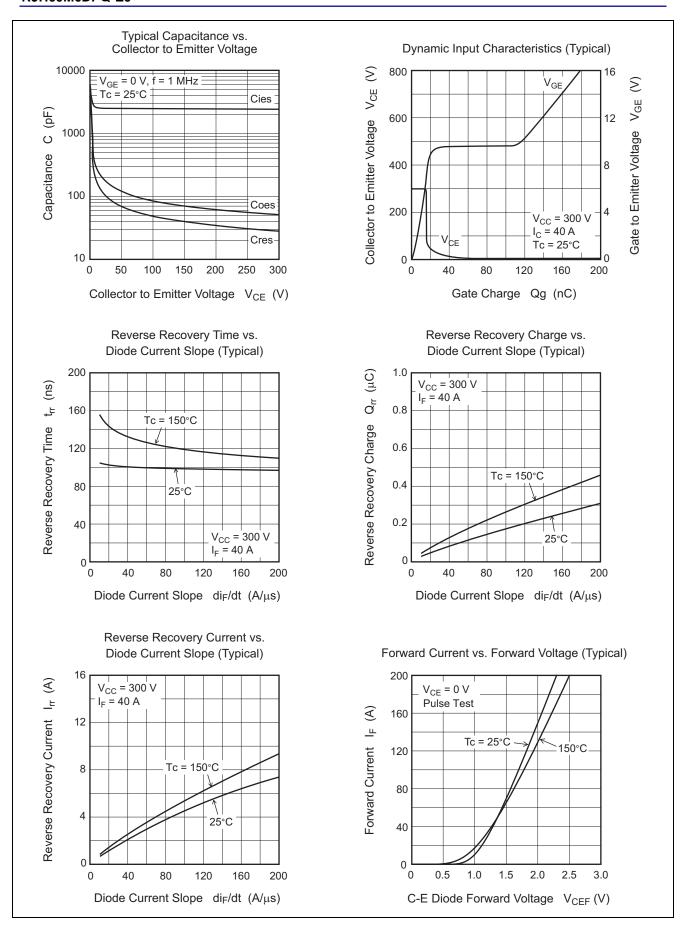
Notes: 3. Pulse test.

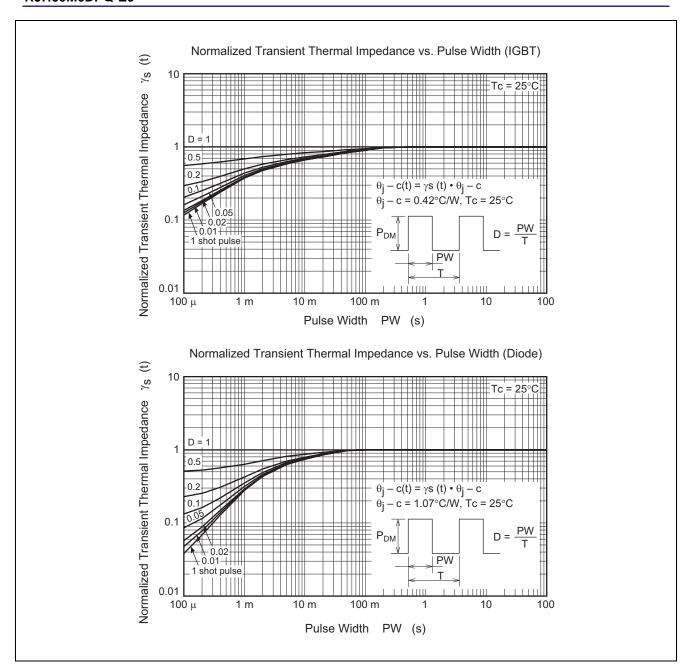
Main Characteristics

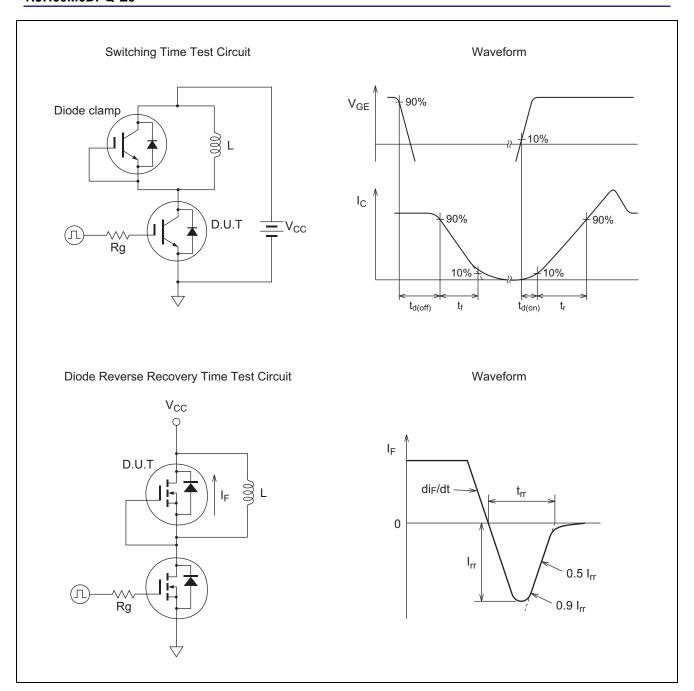




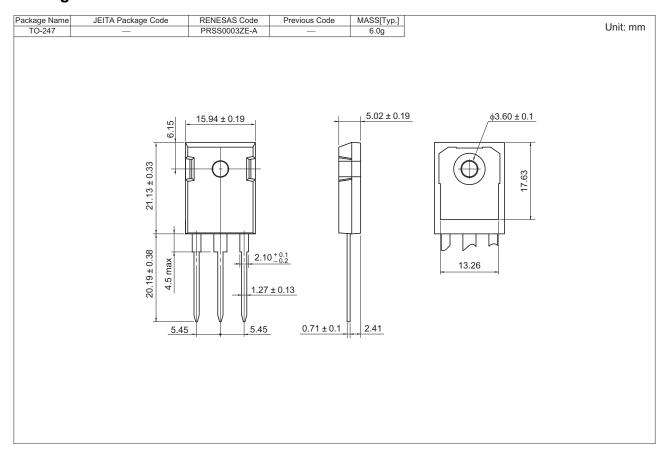








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container	
RJH60M6DPQ-E0#T2	450 pcs	Tube	

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